## **NCE N-Channel Super Trench Power MOSFET**

#### **Description**

The NCEP01T13AD uses **Super Trench** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of  $R_{DS(ON)}$  and  $Q_g$ . This device is ideal for high-frequency switching and synchronous rectification.

#### **General Features**

- $V_{DS}$  =100V, $I_{D}$  =130A  $R_{DS(ON)}$  <4.6mΩ @  $V_{GS}$ =10V
- Excellent gate charge x R<sub>DS(on)</sub> product
- Very low on-resistance R<sub>DS(on)</sub>
- 175 °C operating temperature
- Pb-free lead plating
- 100% UIS tested

## **Application**

- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

100% UIS TESTED

100% ΔVds TESTED!

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Schematic diagram



Marking and pin assignment



TO-263-2L top view

## Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP01T13AD	NCEP01T13AD	TO-263-2L	-	-	-

## Absolute Maximum Ratings (T<sub>C</sub>=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	100	V
Gate-Source Voltage	V <sub>GS</sub>	±20	V
Drain Current-Continuous (Silicon Limited)	I <sub>D</sub>	143	А
Drain Current-Continuous (Package Limited)	I <sub>D</sub>	135	Α
Drain Current-Continuous(T <sub>C</sub> =100°C)	I <sub>D</sub> (100℃)	102	Α
Pulsed Drain Current	I <sub>DM</sub>	500	Α
Maximum Power Dissipation	P <sub>D</sub>	210	W
Derating factor		1.4	W/°C
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	1050	mJ
Operating Junction and Storage Temperature Range	$T_{J}, T_{STG}$	-55 To 175	$^{\circ}$



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#### **Thermal Characteristic**

Thermal Resistance, Junction-to-Case (Note 2)	R <sub>0JC</sub>	0.71	°C/W	1
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Electrical Characteristics (T<sub>C</sub>=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics			•			
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	100		-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =100V,V <sub>GS</sub> =0V	-	-	1	μΑ
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)			•			
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS},I_{D}=250\mu A$	2.5		4.5	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =60A	- 1	3.8	4.6	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =10V,I <sub>D</sub> =60A	-	60	-	S
Dynamic Characteristics (Note4)		O.	•			
Input Capacitance	C <sub>lss</sub>	V =50V/V 20V	-	6400	-	PF
Output Capacitance	Coss	$V_{DS}$ =50V, $V_{GS}$ =0V, F=1.0MHz	_	731	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F-1 OIVI12	_	35	-	PF
Switching Characteristics (Note 4)		G	•			
Turn-on Delay Time	t <sub>d(on)</sub>	0.0	-	19	-	nS
Turn-on Rise Time	tr	V <sub>DD</sub> =50V,I <sub>D</sub> =60A	-	76	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10 $V$ , $R_{G}$ =4.7 $\Omega$	-	48	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	14	-	nS
Total Gate Charge	Qg	\/ -F0\/ L -60A	-	92		nC
Gate-Source Charge	$Q_gs$	$V_{DS}$ =50V, $I_{D}$ =60A, $V_{GS}$ =10V	-	35.4		nC
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> -10V	-	18.8		nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =135A	-		1.2	V
Diode Forward Current (Note 2)	Is		-	-	135	Α
Reverse Recovery Time	t <sub>rr</sub>	$T_J = 25^{\circ}C, I_F = I_S$	-	63		nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs <sup>(Note3)</sup>	-	142		nC

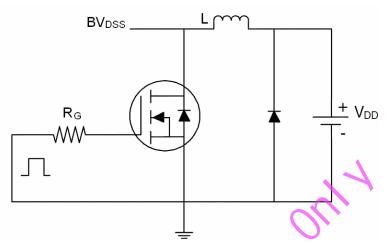
#### Notes:

- ${\it 1. Repetitive Rating: Pulse width limited by maximum junction temperature.}\\$
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width  $\leq$  300 $\mu$ s, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition : Tj=25  $^{\circ}\text{C}$  ,VDD=50V,VG=10V,L=0.5mH,Rg=25 $\Omega$

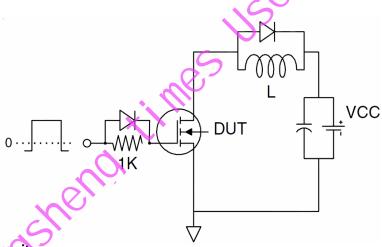


#### **Test Circuit**

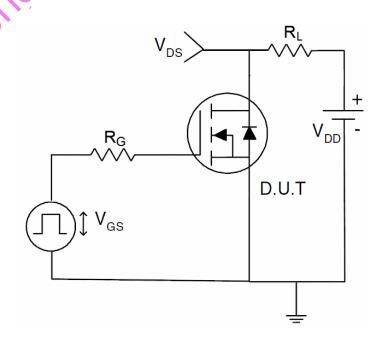
## 1) E<sub>AS</sub> test Circuit



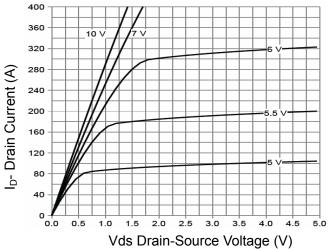
### 2) Gate charge test Circuit



## 3) Switch Time Test Circuit







**Figure 1 Output Characteristics** 

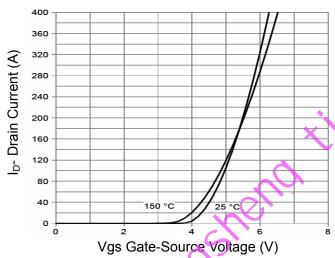


Figure 2 Transfer Characteristics

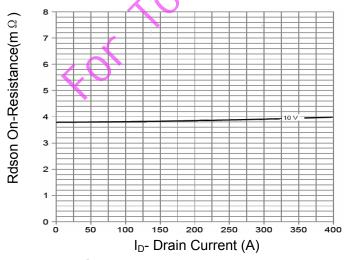


Figure 3 Rdson- Drain Current

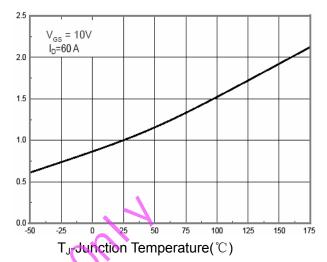


Figure 4 Rdson-JunctionTemperature

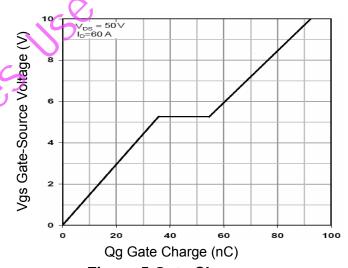


Figure 5 Gate Charge

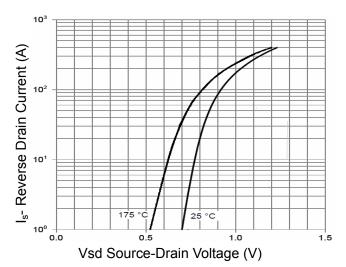


Figure 6 Source- Drain Diode Forward



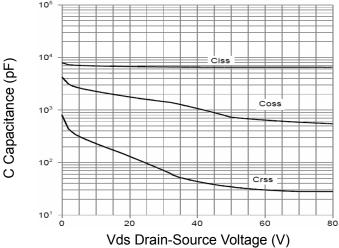


Figure 7 Capacitance vs Vds

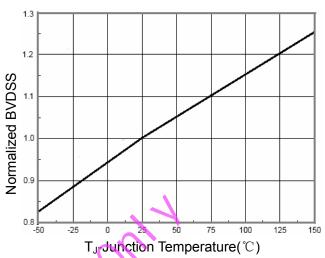


Figure 9 BV<sub>DSS</sub> vs Junction Temperature

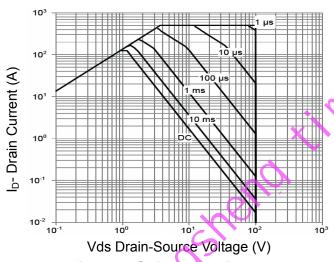


Figure 8 Safe Operation Area

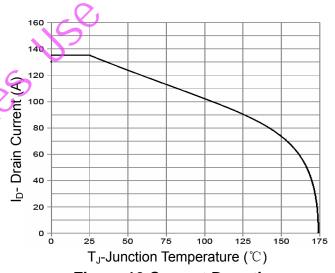
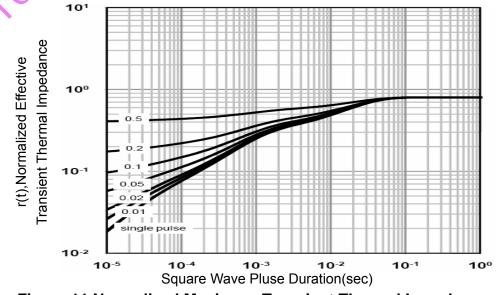


Figure 10 Current De-rating

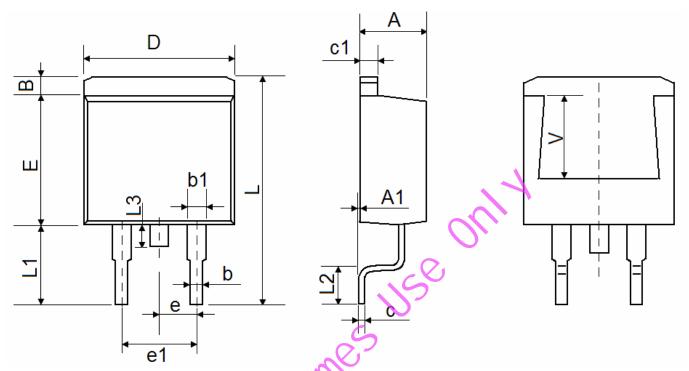


**Figure 11 Normalized Maximum Transient Thermal Impedance** 





## **TO-263-2L Package Information**



Cumbal	Dimensions In Millimeters		Dimensions In Inches	
Symbol	Min.	Max.	Min.	Max.
Α	4.470	4.670	0.176	0.184
A1	0.000	0.150	0.000	0.006
В	1.170	1.370	0.046	0.054
b	0.710	0.910	0.028	0.036
b1	1.170	1.370	0.046	0.054
С	0.310	0.530	0.012	0.021
c1 <u>/</u>	1.170	1.370	0.046	0.054
D	10.010	10.310	0.394	0.406
E 🎸	8.500	8.900	0.335	0.350
е	2.540 TYP.		0.100 TYP.	
e1	4.980	5.180	0.196	0.204
L	15.050	15.450	0.593	0.608
L1	5.080	5.480	0.200	0.216
L2	2.340	2.740	0.092	0.108
L3	1.300	1.700	0.051	0.067
V	5.600 REF		0.220	REF



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